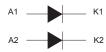
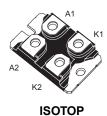




Automotive 100 V, 2 x 120 A, power Schottky rectifier





Features



- PPAP capable
- Operating T_i from -40 °C to +175 °C
- · Low thermal resistance
- Negligible switching losses
- Low C_{J0}
- · High forward surge capability
- Avalanche rated
- Insulated package ISOTOP:
 - Insulated voltage: 2500 V_{RMS} sine
- ECOPACK2 compliant component
- Comply with UL1557 insulation: 2.5 kV
 - Reference file: E81734

Applications

- DC/DC converter, especially in hybrid or electrical vehicles
- OBC
- · Secondary rectification
- · LLC topologies
- · Phase shift topologies

Product status link

STPS240H100TV1Y

Product summary		
Symbol	Value	
I _{F(AV)}	2 x 120 A	
V _{RRM}	100 V	
T _j (max.) 175 °C		
V _F (typ.)	0.610 V	

Description

The STPS240H100TV1Y is an automotive Schottky diode suitable for high frequency switch mode power supply.

Especially suited for DC-DC applications, this isolated ISOTOP Schottky diode will improve the thermal management in harshest environments. Its high forward surge capability ensures a good robustness during transient phases or in case of short circuit event.



1 Characteristics

Table 1. Absolute ratings (limiting values, per diode at T_{amb} = 25 °C, unless otherwise specified)

Symbol	Parameter			Unit
V _{RRM}	Repetitive peak reverse voltage, T_j = -40 °C to +175 °C			V
I _{F(RMS)}	Forward rms current			Α
1	Average forward current S = 0.5 equate wave	T _C = 140 °C, per diode	120	^
I _{F(AV)}	Average forward current, δ = 0.5, square wave	T _C = 140 °C, per device	240	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		1150	Α
P _{ARM}	Repetitive peak avalanche power t_p = 10 μ s, T_j = 125 °C		9300	W
T _{stg}	Storage temperature range			°C
T _j	Maximum operating junction temperature ⁽¹⁾			°C

^{1.} $(dP_{tot}/dT_i) < (1/R_{th(i-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter		Typ. value	Unit
R _{th(j-c)} Junction to case	Per diode	0.24	°C/W	
	Total	0.12	C/VV	

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	T _j = 25 °C	V _R = 15 V	-		40		
I _R ⁽¹⁾	I _R ⁽¹⁾ Reverse leakage current	T _j = 25 °C	V - V	-		90	μA
		T _j = 125 °C	$V_R = V_{RRM}$	-	26	65	mA
	V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 60 A	-		0.700	
		T _j = 150 °C		-	0.505	0.570	
V- (2)		T _j = 25 °C		-		0.750	V
VF (=)		T _j = 150 °C		-	0.545	0.610	v
		T _j = 25 °C	I _F = 120 A	-		0.825	
		T _j = 150 °C	IF - 120 A	-	0.610	0.680	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the maximum conduction losses, use the following equation:

 $P = 0.46 \times I_{F(AV)} + 0.00183 \times I_{F}^{2} (RMS)$

For more information, please refer to the following application notes related to the power losses:

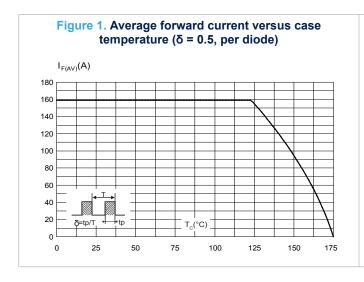
- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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^{2.} Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$



1.1 Characteristics (curves)



Zth(j-c) / Rth(j-c)

1.0

0.9

0.8

0.7

0.6

0.5

0.4

0.3

0.2

0.1

Single pulse

1.E-04

1.E-03

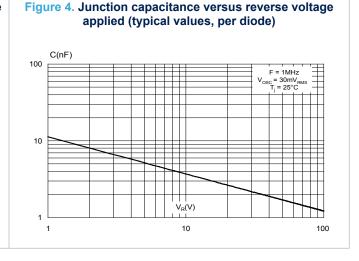
1.E-02

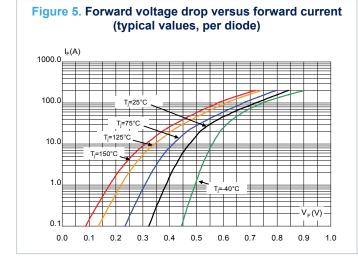
1.E-01

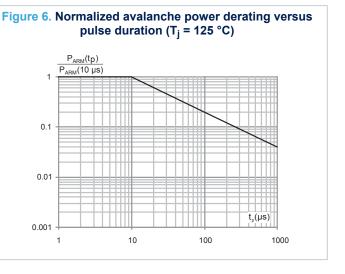
1.E+00

1.E+01

Figure 3. Reverse leakage current versus reverse voltage applied (typical values per diode) $I_R(\mu A)$ 1.E+06 1.E+05 T.= 150°C T_i= 125°C T,= 100°C 1.E+03 T.= 75°C 1.E+02 T.= 50°C 1.E+01 r.= 25°C 1.E+00 $V_{R}(V)$ 0 20 30 50 60 70 80 90 100







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Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 **ISOTOP** package information

Epoxy meets UL94, V0

Cooling method: by conduction (C) Recommended torque value: 1.3 N·m

Maximum torque value: 1.5 N·m

STMicroelectronics strongly recommend the use of the screws delivered with this product. The use of any other screws is entirely at the user's own risk and will invalidate the warranty.

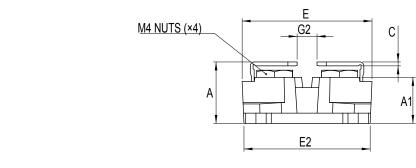


Figure 7. ISOTOP package outline

Gate note 4 Н С D S G D1 В G1 ØΡ

E1

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Table 4. ISOTOP package mechanical data

		Dimensions				
Ref.	Millime	eters	Inches ⁽¹⁾			
	Min.	Max.	Min.	Max.		
А	11.80	12.20	0.460	0.480		
A1	8.90	9.10	0.350	0.358		
В	7.80	8.20	0.307	0.323		
С	0.75	0.85	0.030	0.033		
C2	1.95	2.05	0.077	0.081		
D	37.80	38.20	1.488	1.504		
D1	31.50	31.70	1.240	1.248		
E	25.15	25.50	0.990	1.004		
E1	23.85	24.15	0.939	0.951		
E2	24.8	30	0.976			
G	14.90	15.10	0.587	0.594		
G1	12.60	12.80	0.496	0.504		
G2	3.50	4.30	0.138	0.169		
F	4.10	4.30	0.161	0.169		
F1	4.60	5.00	0.181	0.197		
Н	-0.05	0.10	-0.002	0.004		
Diam P	4.00	4.30	0.157	0.169		
P1	4.00	4.40	0.157	0.173		
S	30.10	30.30	1.185	1.193		

^{1.} Inches given for reference only

For more information, please refer to the following technical note related to the mouting :

TN1331: Assembly recommendations for STMicroelectronics ISOTOP package

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3 Ordering Information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS240H100TV1Y	STPS 240H100TV1Y	ISOTOP	27 g without screws	10 with screws	Tube

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Revision history

Table 6. Document revision history

Date	Version	Changes
18-Feb-2020	1	First issue.
05-May-2020	2	Updated Table 1. Added Mounting information.
08-Jun-2020	3	Updated Figure 3 and inserted TN1331 reference.
12-Jun-2020 4	4	Removed section 3 Mounting information.
	Minor text changes to improve the readibility.	

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CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246

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